

NTE8542 Integrated Circuit Tri-State Quad I/O Register

General Description:

The NTE8542 is a 4-bit storage register with two terminals per bit which may be used as either inputs or outputs when tied to two bus lines. Storage capability is obtained with positive edge triggered flip-flops having common clock and asynchronous clear. Each I/O terminal can be forced to a high impedance state (Hi-z state) using the Output Disable controls.

Features:

Series 54/74 compatible

Input clamp diodes

• Propagation delays 25ns

Power dissipation 400mW

• Operation 40MHz

Absolute Maximum Ratings: (Note 1)

Supply Voltage, V _{CC}	7.0V
Input Voltage, V _i	5.5V
Output Voltage, V _O	5.5V
Storage Temperature Range, T _{stg}	-65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	+300°C

Recommended Operating Conditions:

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	4.75	5.25	V
Temperature	T _A	0	+70	°C

Note 1. "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Electrical Characteristics: (Notes 2 and 3)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Logical "1" Input Voltage	V _{IH}	V _{CC} = Min	2.0	_	_	V
Logical "1" Input Current	I _{IH}	$V_{CC} = Max$, $V_{IN} = 2.4V$ $V_{CC} = Max$, $V_{IN} = 5.5V$	_ _	_	40 1.0	μΑ
Logical "0" Input Voltage	V _{IL}	V _{CC} = Min	_	_	0.8	V
Logical "0" Input Current	I₁∟	$V_{CC} = Max, V_{IN} = 0.4V$	_	-1.0	-1.6	mA
Input Clamp Voltage	V _{CD}	$V_{CC} = Min, I_{IN} = -12mA$	_	_	-1.5	V
Logical "1" Output Voltage	V _{OH}	$V_{CC} = Min, I_{OUT} = -800\mu$	2.4	_	_	V
Output Short Circuit Current	los	V _{CC} = Max, V _{OUT} = 0V, Note 4	-25	-	-70	mA
Logical "0" Output Voltage	V _{OL}	V _{CC} = Min, I _{OUT} = 16mA	-	-	0.4	V
Supply Current	I _{CC}	V _{CC} = Max	-	-	120	mA
TRI-STATE I/O Current with Inputs and Outputs Disabled		$V_{CC} = Max, V_{IN} = 2.4V$ $V_{CC} = Max, V_{IN} = 0.4V$	_ _	_	40 -40	μΑ
Propagation Delay to a Logical "0" from Clock to Output	t _{pd0}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	_	23	35	ns
Propagation Delay to a Logical "0" from Clear to Output	t _{pd0}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	-	24	36	ns
Propagation Delay to a Logical "1" from Clock to Output	t _{pd1}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	_	25	38	ns
Delay from Disable to High Impedance State (from Logical "1" Level)	mpedance State $T_A = 25^{\circ}C$		_	6.0	15	ns
Delay from Disable to High Impedance State (from Logical "0" Level)	t_{0H} $R_{L} = 400\Omega$, $C_{L} = 5.0pF$ $T_{A} = 25^{\circ}C$		_	15	25	ns
Delay from Disable to Logical "1" Level (from High Impedance State)	t _{H1}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	_	20	30	ns
Delay from Disable to Logical "0" Level (from High Impedance State)	t _{H0}	$R_L = 400\Omega$, $C_L = 50pF$ $T_A = 25^{\circ}C$	-	17	25	ns
Maximum Clock Frequency	f _{MAX}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	30	40	_	MHz
Enable to Clock Set-Up Time	t _{SO}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	20	13	_	ns
Enable to Clock Set-Up Time	t _{SI}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	20	12	_	ns

Electrical Characteristics (Cont'd): (Notes 2 and 3)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Date to Clock Set-Up Time	t _{SO}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	10	4.5	-	ns
Date to Clock Set-Up Time	t _{SI}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	5.0	-4.0	ı	ns
Data to Clock Hold Time	t _{HO}	$R_L = 400\Omega$, $C_L = 50pF$ $T_A = 25^{\circ}$	10	4.5	ı	ns
Data to Clock Hold Time	t _{HI}	$R_L = 400\Omega$, $C_L = 50pF$ $T_A = 25^{\circ}C$	5.0	-3.5	ı	ns
Minimum Clock Pulse Width	PW _{MIN}	$R_L = 400\Omega$, $C_L = 50pF$ $T_A = 25^{\circ}C$	20	-	-	ns
Minimum Clear Pulse Width	PW _{MIN}	$R_L = 400\Omega, C_L = 50pF$ $T_A = 25^{\circ}C$	20	_	1	ns

- Note 2. Unless otherwise specified min/max limits apply across the 0°C to +70°C range for the NTE8542. All typicals are given for $V_{CC} = 5.0 V$ and $T_A = 25 °C$.
- Note 3. All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to GND unless otherwise noted. All values shown as max or min on absolute value basis.

MODE OF OPERATION:

CLEAR	DIS ₁	DIS ₂	E ₁	E ₂	A ₁₋₄	B _{1 - 4}	Comments
0	0	1	1	1	Q	Hi–z	Output Data to Bus A
0	1	0	1	1	Hi–z	Q	Output Data to Bus B
0	0	0	1	1	Q	Q	Output Data to Both Buses
0	1	1	1	1	Hi–z	Hi–z	Store Data With Outputs in Hi-z State
0	Х	Х	0	1	Data	Q _N	Enter Data From Bus A
0	Х	Х	1	0	Q _N	Data	Enter Data From Bus B
0	Х	Х	0	0	Data	Data	Enter Data From Both Buses (Logic "1" on Either Will Dominate)
1	Х	X	Х	Х	Х	Х	Clear

X = Don't Care State

Q_N = Data After Clock Transition

